Diode Semiconductor Device - Page 1 of 1



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| Inclosure | Materiai: |
|-----------------------|--|
| Glass | |
| Overall Le | ength: |
| Between 0 | 0.160 inches and 0.205 inches |
| Terminal I | Length: |
| 1.100 inch | es |
| Overall Di | ameter: |
| Between 0 | 0.080 inches and 0.107 inches |
| Joint Elec | tronic Device Engineering Council/jedec/case Outline Designation |
| Do-41 | |
| Mounting | Method: |
| Terminal | |
| Features I | Provided: |
| Hermetical | Ily sealed case |
| Criticality | Code Justification: |
| Feat | |
| Semicond | luctor Material: |
| Silicon | |
| Voltage R | ating In Volts Per Characteristic: |
| 200.0 reve | erse voltage, peak |
| Current R | ating Per Characteristic: |
| 750.00 mil | liamperes average forward current averaged over a full 60-hz cycle |
| Special Fe | eatures: |
| Weapon s | ystem essential |
| Terminal ⁻ | Type And Quantity: |
| 2 uninsulat | ted wire lead |
| Shelf Life: | : |
| N/a | |
| Unit Of Me | easure: |
| | |
| Demilitari | zation: |
| No | |
| Fiig: | |
| - | |